

**DESCRIPTION**

This UPS560e3 in the Powermite3<sup>®</sup> package is a high efficiency Schottky rectifier that is also RoHS compliant offering high current/power capabilities previously found only in much larger packages. They are ideal for SMD applications that operate at high frequencies. In addition to its size advantages, the Powermite3<sup>®</sup> package includes a full metallic bottom that eliminates the possibility of solder flux entrapment during assembly and a unique locking tab act as an efficient heat path to the heat-sink mounting. Its innovative design makes this device ideal for use with automatic insertion equipment.

**IMPORTANT:** For the most current data, consult MICROSEMI's website: <http://www.microsemi.com>


**KEY FEATURES**

- Very low thermal resistance package
- RoHS Compliant with e3 suffix part number
- Guard-ring-die construction for transient protection
- Efficient heat path with Integral locking bottom metal tab
- Low forward voltage
- Full metallic bottom eliminates flux entrapment
- Compatible with automatic insertion
- Low profile-maximum height of 1mm

**ABSOLUTE MAXIMUM RATINGS AT 25° C  
(UNLESS OTHERWISE SPECIFIED)**

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	60	V
RMS Reverse Voltage	$V_{R(RMS)}$	42	V
Average Rectified Output Current	$I_o$	5	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine wave Superimposed on Rated Load@ $T_c = 90^\circ C$	$I_{FSM}$	100	A
Storage Temperature	$T_{STG}$	-55 to +150	°C
Junction Temperature	$T_J$	-55 to +125	°C

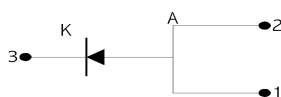
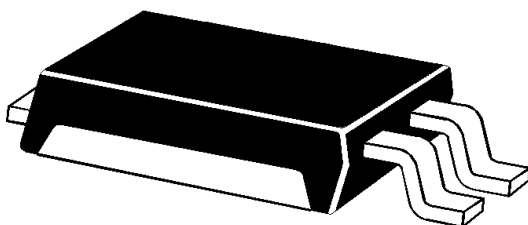
**APPLICATIONS/BENEFITS**

- Switching and Regulating Power Supplies.
- Silicon Schottky (hot carrier) rectifier for minimal reverse voltage recovery
- Elimination of reverse-recovery oscillations to reduce need for EMI filtering
- Charge Pump Circuits
- Reduces reverse recovery loss with low  $I_{RM}$
- Small foot print  = 190 X 270 mils (1:1 Actual size)  
See mounting pad details on pg 3

**THERMAL CHARACTERISTICS**
**Thermal Resistance**

Junction-to-case (bottom)	$R_{\theta JC}$	3.2	°C/ Watt
Junction to ambient (1)	$R_{\theta JA}$	65	°C/ Watt

(1) When mounted on FR-4 PC board using 2 oz copper with recommended minimum foot print

**Powermite 3™**


Note: 1 Short duration test pulse used to minimize self – heating effect.

**MECHANICAL & PACKAGING**

- CASE: Void-free transfer molded thermosetting epoxy compound meeting UL94V-0
- FINISH: Annealed matte-Tin plating over copper and readily solderable per MIL-STD-750 method 2026 (consult factory for Tin-Lead plating)
- POLARITY: See figure (left)
- MARKING: S560•
- WEIGHT: 0.072 gram (approx.)
- Package dimension on last page
- Tape & Reel option: 16 mm tape per Standard EIA-481-B, 5000 on 13" reel

**ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)**

Parameter	Symbol	Conditions	Min	Typ.	Max	Units
Forward Voltage (Note 1)	$V_{Fm}$	$I_F = 5\text{ A}, T_J = 25^\circ\text{C}$ $I_F = 5\text{ A}, T_J = 125^\circ\text{C}$ $I_F = 8\text{ A}, T_J = 25^\circ\text{C}$ $I_F = 8\text{ A}, T_J = 125^\circ\text{C}$		0.65 0.56 0.74 0.64	0.69 0.60 0.78 0.68	V
Reverse Break Down Voltage (Note 1)	$V_{BR}$	$I_R = 0.2\text{ mA}$	60			V
Reverse Current (Note1)	$I_{rm}$	$V_R = 60\text{ V}, T_J = 25^\circ\text{C}$ $V_R = 60\text{ V}, T_J = 125^\circ\text{C}$		2 0.6	200 20	$\mu\text{A}$ mA
Capacitance	$C_T$	$V_R = 4\text{ V}; F = 1\text{ MHz}$		150		pF

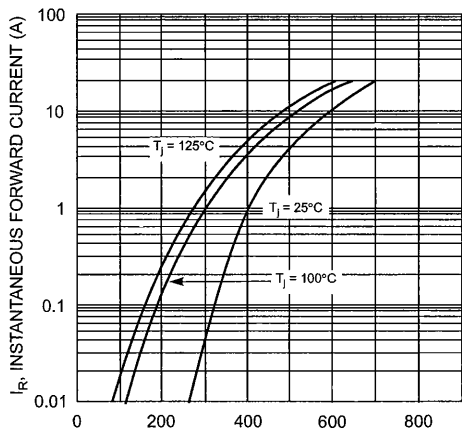
**GRAPHS**


Fig. 1 Typical Forward Characteristics

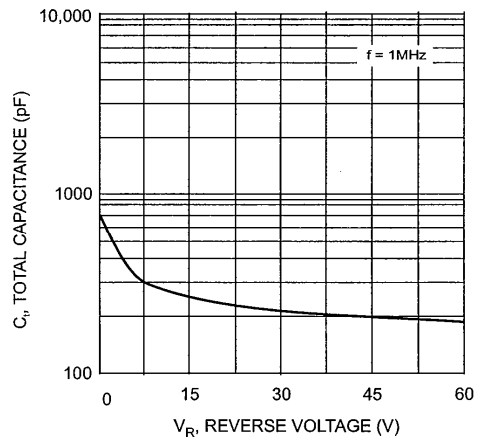


Fig. 3 Typical Capacitance vs. Reverse Voltage

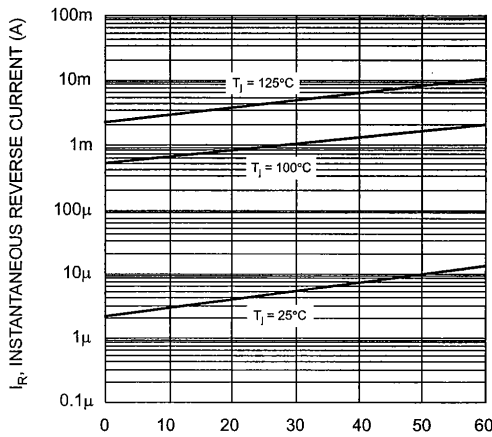


Fig. 2 Typical Reverse Characteristics

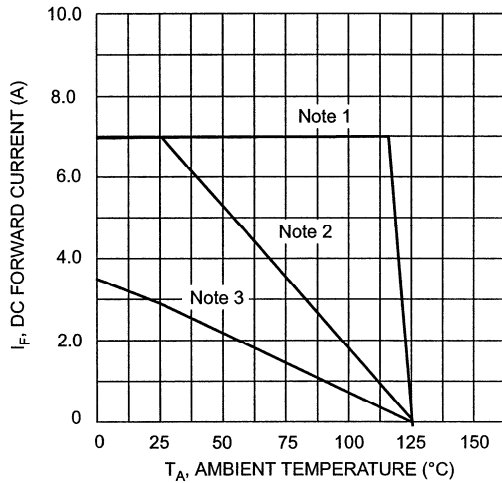


Fig. 4 DC Forward Current Derating

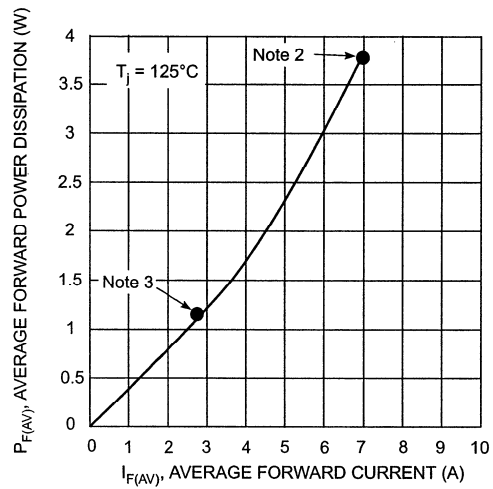
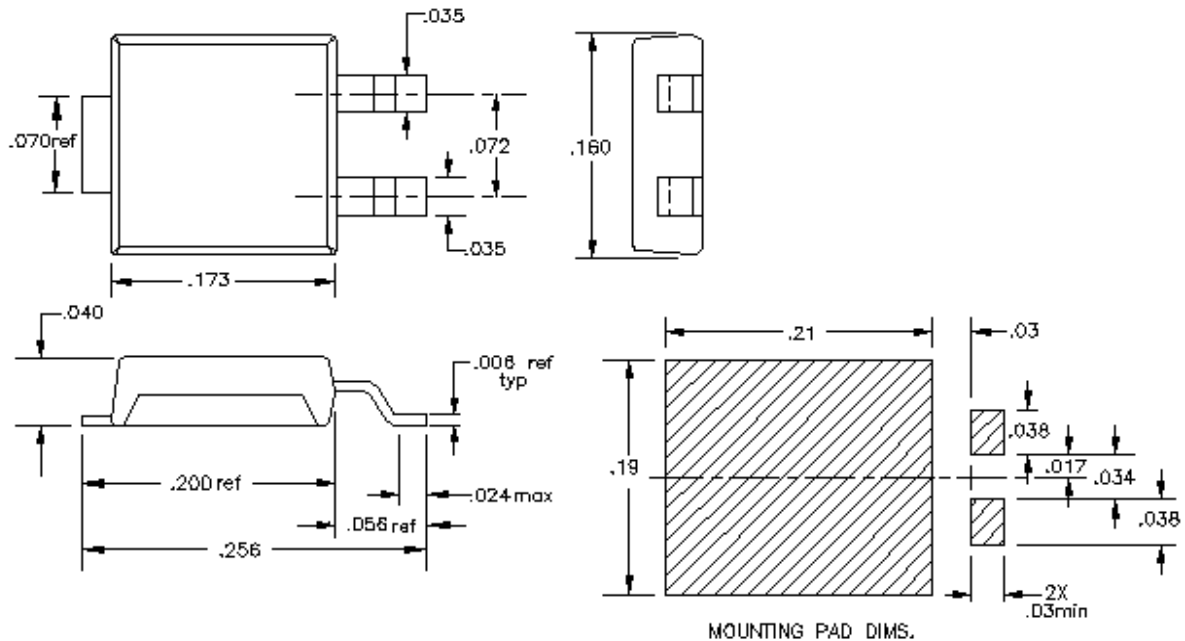


Fig. 5 Forward Power Dissipation

NOTE 1:  $T_A = T_C$  at case bottom where  $R_{\theta JC} = 2.5^\circ \text{C/W}$  and  $R_{\theta CA} = 0^\circ \text{C/W}$  (infinite heat sink).

NOTE 2: Device mounted on GETEK substrate, 2" x 2", 2 oz. copper, double-sided, cathode pad dimensions 0.75" x 1.0", anode pad dimensions 0.25" x 1.0".  $R_{\theta JA}$  in range of 20-35° C/W.

NOTE 3: Device mounted on FRA-4 substrate, 2" x 2", 2 oz. copper, single-sided, pad layout  $R_{\theta JA}$  in range of 65°C/W. See

**PACKAGE & MOUNTING PAD DIMENSIONS (inches)**


NOTE: LEAD FRAMES ARE Sn/Pb PLATED.